

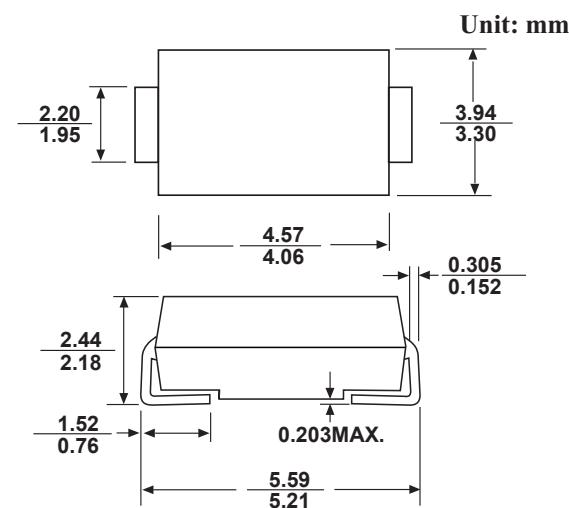
SMB Ultra-Fast Recovery Rectifier Diodes

FEATURES

- For surface mounted applications
- Low profile package
- Glass Passivated Chip Junction
- Superfast reverse recovery time
- Lead free in comply with EU RoHS 2011/65/EU directives

MECHANICAL DATA

- Case: SMB molded plastic body
- Terminals: Solder plated, solderable per MIL-STD-750, Method 2026
- Polarity: Color band denotes cathode end
- Mounting Position: Any



MAXIMUM RATINGS AND CHARACTERISTICS

@ 25°C Ambient Temperature (unless otherwise noted)

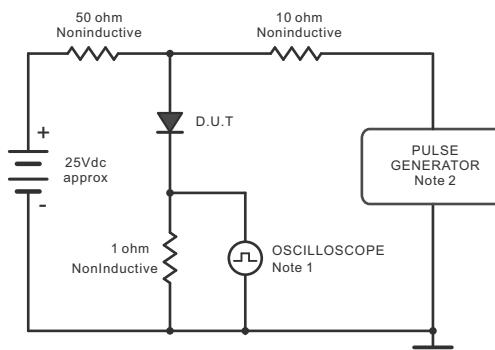
Parameter	Symbol	ES5A	ES5B	ES5C	ES5D	ES5E	ES5G	ES5J	UNITS		
Maximum recurrent peak reverse voltage	V_{RRM}	50	100	150	200	300	400	600	V		
Maximum RMS voltage	V_{RMS}	35	70	105	140	210	280	420	V		
Maximum DC blocking voltage	V_{DC}	50	100	150	200	300	400	600	V		
Maximum Average Forward Rectified Current.375"(9.5mm) Lead Length at $T_A=55^\circ\text{C}$	$I_{F(AV)}$	5.0						A			
Peak Forward Surge Current, 8.3 ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	100.0						A			
Maximum Instantaneous Forward Voltage at 5.0A	V_F	1.0		1.25		1.7	V				
Maximum reverse current at rated DC blocking voltage	I_R	5.0 100.0						μA			
$@T_A=25^\circ\text{C}$											
Maximum reverse recovery time (Note1)	t_{rr}	35.0						ns			
Typical Junction Capacitance at $VR=4\text{V}$, $f=1\text{MHz}$	C_J	50.0						pF			
Typical thermal resistance(Note2)	$R_{\theta JA}$	40.0						$^\circ\text{C}/\text{W}$			
	$R_{\theta JC}$	15									
Operating and Storage Temperature Range	T_j, T_{stg}	-55 ~ +150						$^\circ\text{C}$			

Note: 1.Reverse recovery condition $I_F=0.5\text{A}, I_R=1.0\text{A}, I_{rr}=0.25\text{A}$

2.P.C.B. mounted with $0.2 \times 0.2''(5.0 \times 5.0\text{mm})$ copper pad areas

RATINGS AND CHARACTERISTIC CURVES

Fig.1 Reverse Recovery Time Characteristic And Test Circuit Diagram



Note: 1. Rise Time = 7ns, max.
Input Impedance = 1megohm,22pF.
2. Ries Time =10ns, max.
Source Impedance = 50 ohms.

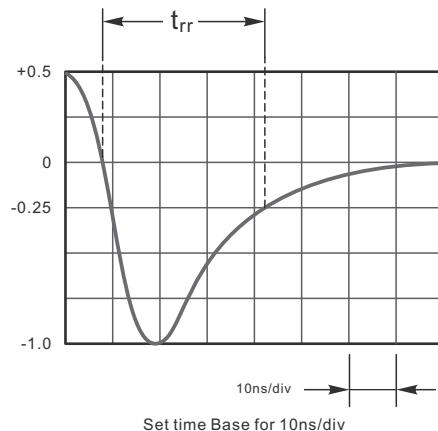


Fig.2 Maximum Average Forward Current Rating

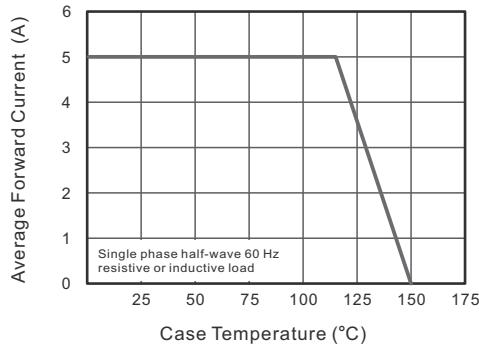


Fig.3 Typical Reverse Characteristics

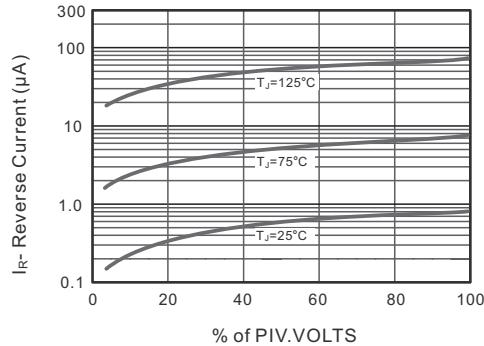


Fig.4 Typical Forward Characteristics

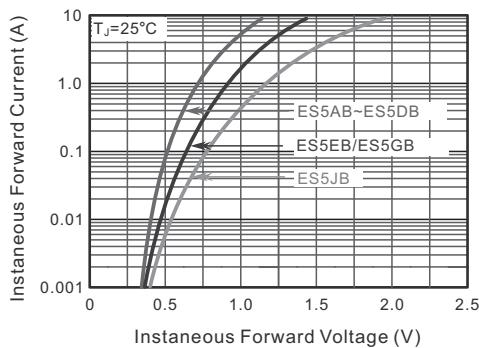


Fig.5 Typical Junction Capacitance

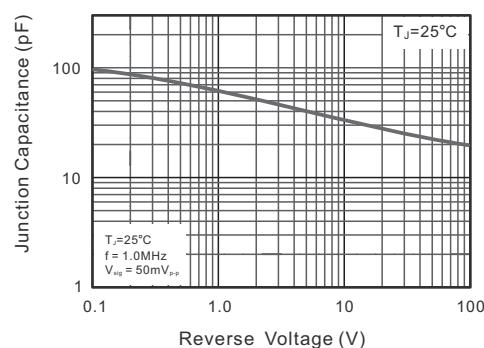


Fig.6 Maximum Non-Repetitive Peak Forward Surge Current

